# Lattice gas m odels of coherent strained epitaxy

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## Abstract

The harm onic Frenkel-K ontorova model is used to illustrate with an exactly solvable example a general technique of mapping a coherently strained epitaxial system with continuous atom ic displacements onto a lattice gas model (LGM) with only discrete variables. The mist strain of the original model is transformed into cluster interatom ic interactions of the LGM. The clusters are contiguous atom ic chains of all lengths but the interaction strength for long chains is exponentially small. Thism akes possible the application of e cient M onte C arb techniques developed for discrete variables both in kinetic and equilibrium simulations. The form alism developed can be applied to 1D as well as to 2D system s. A san illustrative example we consider the problem of self-organization of 1D size calibrated clusters on the steps of the vicinal surfaces.

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The phenom ena of self-assembly and self-organization of coherent (i.e., dislocation-free) size calibrated nano-and atom ic-scale structures observed during the heteroepitaxial grow th in some system  $s^{1,2}$  are considered to be promising tools for fabrication of microelectronic devices<sup>3</sup>.

A major factor in uencing the phenom enon of self-assembly is the lattice size m is t (LSM) between the substrate and the growing overlayer commonly encountered in heteroepitaxial system  $s^4$ . The LSM -induced strain is believed to be the driving force behind the above phenom ena<sup>4,5</sup>. So an adequate account of the strain e ects should lie at the basis of any theory of strained epitaxy. Because strained systems exhibit complicated kinetics and morphologies, analytic approach is di cult, so a major technique in theoretical studies of strained epitaxy is the kinetic M onte C arlo simulation. The application of this technique, however, is severely ham pered by the necessity to simulate the continuous atom ic displacements. Because of this, atom istic models in such simulations are currently restricted to rather sm all system s consisting of only a few thousand atom s<sup>6</sup> while experimentally observed 3D quantum dots sometimes consist of several tens of thousand atom s each<sup>2</sup>.

Our research is based on the observation that as long as we are interested only in the coherent structures, there is a possibility to map the system onto a purely lattice model because in the absence of dislocations the relaxed atom can only either deviate from its symmetric position inside the same cell or to be displaced to another cell but there always exists a lattice site of a regular lattice to which this atom can be ascribed. So our rst goal is to develop a form alism which would allow to map a coherent heteroepitaxial system with the continuous variables onto a lattice gas model with only discrete variables.

O ne of important goals of the heteroepitaxial studies is the development of techniques of growth of 1D quantum wires (QW) which can be used, e.g., for experimental investigation of the Luttinger model of interacting 1D electrons<sup>7</sup>. Furthermore, the QW may not application in microelectronics circuitry<sup>3</sup>, as well as in magnetic memory devices<sup>8</sup>. The latter applications would require the 1D structures of nite length. In the case of the memory devices it is also desirable that these atom ic clusters (or chains) were of similar length and that they were arranged into periodic arrays in order to simplify the memory access. All these requirements can be satisfied by self-organized size calibrated structures similar to

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quantum dots of the 2D epitaxy<sup>2</sup>. A phenom enological theory explaining the mechanism of form ation of quantum dots was proposed in  $\text{Ref.}^5$ . The theory is quite general and can be applied to objects in any number of dimensions. So to illustrate the techniques developed in the present paper we will study the conditions of form ation of the 1D size calibrated monatom ic chains.

#### II. THE MODEL

A simple approach to theoretical description of the m is t is provided by the 1D Frenkel-K ontorova m odel (FKM) which is frequently been used in qualitative<sup>9,10</sup> and sem iquantitative studies<sup>11</sup> of strained epitaxy. To illustrate the generality of our approach we

rst present the form alism appropriate to the 2D epitaxy but in concrete examples we will restrict ourselves to the 1D case.

We consider an ensemble of a xed number (N) of atom s coherently deposited on a surface with a square lattice of deposition sites. The rectangular lattice geometry was chosen because it allows for the separation of x and y variables (see R ef.<sup>9</sup> and below). Let us rst consider more generalm odel with the energy of the epilayer of the form

$$U = \sum_{i}^{X} n_{i}V_{s}(R_{i} + u_{i}) + \frac{1}{2}\sum_{ij}^{X} n_{i}n_{j}V(u_{i} + R_{i} - u_{j} - R_{j});$$

where  $R_i = (a^x i_x; a^y i_y)$  (a the lattice constants in the two directions,  $i_x$  and  $i_y$  integers),  $n_i = 0;1$  is the occupation number of site i,  $u_i$  the atom ic displacement,  $V_s$  the potential of interaction with the substrate, and V the interatom ic potential.

The analysis of the system considerably simpli es at low temperatures where it can be approximately reduced to a lattice gas model. This is achieved by exploiting the fact that the residence time of atoms at the lattice sites can be arbitrarily large due to the A menius law obeyed by the probability of activated hopping over the potential barriers separating neighboring sites<sup>12</sup>. The dynam ics of the variables  $u_i$ , on the other hand, do not have any energy barriers. So at su ciently low temperature these variables are capable of reaching their therm all equilibrium distribution during the time intervals between the atom ic hops, i. e., with the atom ic conguration remaining unchanged. A veraging over  $u_i$  will leave us with an elective non-equilibrium free energy function  $F_e$  of variables  $n_i$  only:

exp(
$$F_e = k_B T$$
) =  $\int_{f_{n_i}=1q}^{2} du_i exp(U=k_B T)$ : (1)

This purely lattice model can be further used in both equilibrium and kinetic studies.

For the purposes of qualitative analysis it will su ce to average out the displacement variables in Eq. (1) in the harmonic approximation, i. e., by expanding  $V_s$  and  $V_p$  in the above equation up to the second order in the displacement variables  $u_i^{11,13}$  which is valid for small  $ju_i j=a$ . This allows to perform the calculation exactly (see below). However, the integration can be extended to approximately account also for anharmonic terms. This extension, besides making the approach more accurate, can also account for some qualitative phenom ena<sup>10</sup>.

To facilitate comparison with other studies based on the Frenkel-K ontorova m odel<sup>9,10,11,14</sup> we write the harm onic approximation as the second order power series expansion in  $u_i$  for  $V_s$  and in  $u_i$   $u_i$  for the pair potential  $V_p$ :

$$U = V_{s}N + \frac{1}{2} \sum_{i}^{X} n_{i}k_{s} (u_{i})^{2} + \frac{1}{2} \sum_{ij}^{X} n_{i}n_{j}V_{ij}$$
  
+  $\frac{1}{2} \sum_{i}^{X} k_{p} [(u_{i} \quad u_{i+} \quad f)^{2} \quad f^{2}]n_{i}n_{i+}$   
=  $V_{s}N + \frac{1}{2} \sum_{ij}^{X} V_{ij}n_{i}n_{j}$   
+  $\frac{1}{2} \sum_{ij}^{X} k_{p}D_{ij}u_{i}u_{j} + \sum_{i}^{X} k_{p}f u_{i}r_{i}n_{i+}$  (2)

where  $V_s$  and  $V_{ij}$  are the values of the substrate and the pair potentials at the lattice sites for the atom in the symmetric position (the zero order approximation), denotes x or y component;  $f = V^0 = V^0$  (where V is the pair potential) is interpreted as the m is t parameter in the direction ,  $k_s$  and  $k_p$  are the second derivatives of the corresponding potentials,  $D_{ij}$  is the dimensionless dynamical matrix de ned by this equality, and  $r_i F_i$  $F_i \ F_i \ A$  major simplication is achieved under the nearest neighbor (NN) approximation for the relaxation because, as is seen from the last line of Eq. (2), in this case the variables  $u_i^x$  and  $u_i^y$  separate, and the relaxations along the two directions are independent.

W ith approximation (2) the statistical average amounts to the Gaussian integration to give

$$F_{e} = V_{s}N + \frac{1}{2} \sum_{ij}^{X} n_{i}n_{j}V_{ij} + \frac{k_{B}T}{2} \sum_{ij}^{X} \ln \det G$$

$$\frac{k_{p}f^{2}}{2} \sum_{ij}^{X} G_{ij}r_{i}n_{i}n_{i^{+}} + r_{j}n_{j}n_{j^{+}}; \qquad (3)$$

where G = 1=D and in  $V_s$  we gathered all term swhich are proportional to the total particle number, such as the normalization of the determinant coming from the in-plane Gaussian integration and a similar term from the integration along z-direction. We do not discuss these contributions here because in the present study we restrict ourselves to system swith a

xed number of deposited atom sN. In case of necessity these terms can be easily recovered. We also note the entropic contribution (the second term in the rst line) which naturally appears in our formalism and which was shown to be crucial for proper description of the processes of deposition<sup>15</sup> as well as for the correct prediction of the shape of the atom ic clusters<sup>16</sup>.

Because of the gradient factors, only the ends of contiguous chains of atom s contribute into the last term of Eq. (3) leaving two matrix elements of  $G_{ij}$  in the sum over ij inside every chain: the diagonal one which we denote as  $G_1^{(0)}$  (1 the length of the chain; we om it the superscript to simplify notation) and the matrix element  $G_1^{(1-1)}$  connecting the two ends of the chain. Furthermore, in the NN approximation the matrix D is block-diagonal because the atom s belonging to dimension of the free energy which consists of the term s in Eq. (3) containing G takes the form

$$F_{\text{relax}} = \sum_{\substack{X \text{ chains}}}^{X} f \frac{k_{\text{B}} T}{2} \ln \det \frac{G_{1}}{G_{1}} + k_{\text{p}} f^{2} [G_{1}^{(0)} - G_{1}^{(l-1)}]g$$

$$X^{\text{chains}} (TS_{1} + W_{1}) = E_{1}; \qquad (4)$$

$$G^{\text{chains}} = G^{\text{chains}}$$

where the summation is over the chains consisting of two or more atoms. Besides, in the rst term on the right hand side (r. h. s.) we subtracted the single atom entropy term by assuming that it is accounted for in  $V_s$  which we discarded to simplify notation. It is easy to show that  $F_{relax}$  can be expanded into an in nite sum of multiatom interactions of the form  $V_1n_in_{i^+} \cdot :::n_{i^+} (1 \ 1)^{\wedge}$ , where  $^{\circ}$  is the unit vector in the direction  $^{\circ}$ . The expansion coelected are given by the expression

$$V_1 = E_1 \quad 2E_{1\,1} + E_{1\,2} \tag{5}$$

valid for all  $2 \text{ with } E_0 = E_1 = 0$ .

0

O m itting the superscript to simplify notation, the matrix  $D_1$  for chain of length 1 is dened according to Eq. (2) as

$$k_{p} \prod_{ij}^{X} (D_{1})_{ij} u_{i} u_{j} = k_{s} u_{1}^{2} + k_{p} (u_{1} u_{2})^{2} + k_{s} u_{2}^{2} + \dots + k_{p} (u_{1} u_{1})^{2} + k_{s} u_{1}^{2}$$
(6)

Hence, the square m atrix  $k_p D_1$  have the following structure:

$k_pD_1 =$	aaaaaaaaaaaaaaaaaaaaaaaaaaaaaaaaaaaaaa	<sub>p</sub> + k <sub>s</sub>	k <sub>p</sub>	0	:::	0	0	0		
		kp	$2k_p + k_s$	kp	0	:::	0	0	Ĉ	
		0	kp	$2k_p + k_s$	kp	0	:::	0	CCC	
	nunun	: 0	• •	•.	•••	•••	•		CCCC	(7)
	BARARA		:::	0	kp	$2k_p + k_s$	kp	0	CCC	
		0	0	:::	0	kp	$2k_p + k_s$	kp		
	BB@  _	0	0	0	<b>:::</b>	0	kp	$k_p + k_s$	C A	
	-				1					

In Appendix A we have shown that them atrix elements of  $G_1 = 1 = D_1$  entering the expression for the relaxation free energy (4) can be calculated with the use of recursion formulas for the tridiagonalm atrices as [see Eqs. (A 10) and (A 11)]

$$\overset{8}{\leq} G_{l+1}^{(0)} = 1 = (1 + d_{l})$$

$$\overset{(0)}{\leq} G_{l+1}^{(0)} = \det G_{l+1} = G_{l+1}^{(0)} b_{l};$$
(8)

1

where  $= k_s = k_p$ ;  $d_l$  and  $b_l$  are generated by the recursion relations

$$d_{l+1} = 1 = (2 + d_1)$$
 and  $b_{l+1} = d_{l+1}b_l$ : (9)

The recursion relations (9) at large 1 drive  $d_1$  and  $b_1$  to the xed point  $d_1$ ;  $b_2$ :

$$d_{2} = 1 + \frac{2}{2} + \frac{2}{4} < 1$$
(10)

$$b_{2} = 0:$$
 (11)

This means that at large  $1 G_1^{(0)}$  saturates to a constant value while  $G_1^{(1)} = \det G_1 \quad d_2^1$ [see Eqs. (8)]. This in particular means that the entropic contribution into  $F_{relax}$  which is proportional to  $\ln (\det G_1)$  is asymptotically linear in 1 (see Fig. 1). Two contributions into  $F_{relax}$  calculated with these form ulas are shown in Fig. 1. The entropic contribution is negative because in our canonical ensemble form alism we discarded the entropy corresponding to N isolated atom s which is rejected in the denominator  $G_1$  in the expression (4) for the free energy. This means, in particular, that when  $k_p ! 0$  the atom ic displacements within the cell became mutually independent (the on-site pair interactions do not depend on the atom ic positions inside the cell), so  $G_1 ! G_1 \hat{f}$ , where  $\hat{f}$  is the unit matrix, and the entropy term tends to zero [see Eq. (4) and Fig.1]. When  $k_p$  is not equal to zero, the atom ic displacements became restricted by its neighbors, so their entropy diminishes. For large chains the interior atom s are practically in translationally invariant environment, so for long chains the entropy loss is proportional to 1. The above restrictions on the atom ic displacements are the more stringent the larger  $k_p$ . This is rejected in the slope of  $S_1$  which is larger for smaller =  $k_s = k_p$  (see Fig.1).

Because the entropic contribution in Eq. (4) is multiplied by T, at low temperature it can be neglected. The remaining term W<sub>1</sub> is negative and saturates to a nite value at large 1 (see Fig. 1b). From Eq. (2) it follows that the NN interatom ic interaction  $V_{\rm NN} = V_{\rm NN}^{\rm ch} + k_{\rm p}f^2$ , where the rst term ( $V_{\rm NN}^{\rm ch}$ ) is some \chemical" interaction and the second term is the unrelaxed repulsion due to LSM. Thus, the relaxation energy in Eq. (4) is the di erence between the relaxed elastic energy of the chain  $E_{\rm rel}^{\rm el}(1)$  and the unrelaxed one  $E_0^{\rm el}(1) = (1 - 1)k_{\rm p}f^2$  with both energies being positive, as it should be for elastic energies. Thus,

$$W_1 = E_{rel}^{el}(1) = E_0^{el}(1)$$

and is negative because relaxation lowers the energy. Now, if  $V_{NN}^{ch}$  is negative but such that  $V_{NN}$  is not too large, then the reduced chain energy  $[N_1 + V_{NN} (l 1)] = lw$  ill have a m in imum corresponding to an equilibrium chain length. In two dimensions these chains will unify in square platelets. Thus, our model contains the mechanism for the size calibration of atom ic clusters which was phenom enologically described in Ref.<sup>5</sup>. In 2D this conclusion as well as the form ula of Ref.<sup>5</sup> were veriled with the use of the M onte C arlo simulation<sup>17</sup>.

Because the entropic contribution  $S_1$  (see Fig. 1a) is practically linear in l according to Eq. (5) which has the form of the discrete second derivative it essentially contributes only into the pair interaction  $V_2$  (the multiatom contributions were found to be 10%). Thus, the relaxation entropy form ally amounts to e ective NN interatom ic repulsion which grows linearly with temperature. The entropic forces of this kind were earlier discovered in alloys

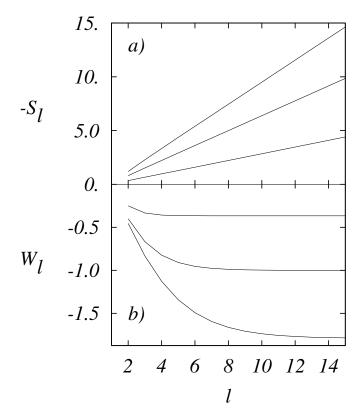


FIG.1: Relaxation entropy in units of  $k_B$  (a) and relaxation energy in units of  $k_p f^2$  (b) for chains of length 1. At both gures the rst curve from the horizontal zero axis corresponds to = 2, the second to = 0.5, and the third one to = 0.2 (note di erence in scale).

(see Appendix E of Ref.<sup>18</sup> and references to earlier literature therein).

At low temperature the main contributions into  $V_1$  for 1 3 come from  $W_1$  (Fig.1b). Because the r.h. s. of Eq. (5) has the form of the discrete second derivative and the curve  $W_1$ (1) is concave, all multiatom interactions are repulsive. On the other hand, in the case under consideration when atom s are supposed to assemble into clusters, there should exist attractive interactions which in our model are necessarily the pair ones [see Eq. (2)].

## IV. EXAMPLES FROM METALLIC HETEROEPITAXIAL SYSTEMS

To illustrate the above form alism with realistic examples of strained epitaxy we consider twom etallic heteroepitaxial systems | Ag/Pt and Pt/Co| which currently are being actively studied both experimentally<sup>19,20,21</sup> and theoretically<sup>22,23</sup>. For simplicity we considered 1D case and used the geometry of Ref.<sup>24</sup> where the growth on the steps of the closed packed (111) vicinal surface was studied. The position of a deposited atom was relaxed to its equilibrium value in order to nd the value  $k_s$  as the second derivative of the potential near equilibrium. The many-body \potentials" and corresponding parameters were taken

		$k_p f^2$ (eV)	$V_{N \ N}$ (eV)
0%	0.32	0.049	-0,218
2%	0.25	0.100	-0.179
3%	0.22	0.136	-0.152

TABLE I: Param eters corresponding to the Pt/Co heteroepitaxial system

from  $\operatorname{Ref.}^{24}$  for the Ag/Pt system and from  $\operatorname{Ref.}^{23}$  for the Pt/Co system. These potentials were devised speci cally to application in the heteroepitaxy and for the (111) surfaces so we expect our results below are quite reliable. O ther parameters listed in Table IV were calculated for the atom ic pairs relaxed only in vertical position because in our approach we need the rst and second derivatives [see discussion after Eq. (2)] calculated in the center of of symmetry of the 1D cell. In both calculations only the NN interactions were taken into account because the NNN ones were found to be negligeable.

A coording to our calculations the Ag/Pt system has the following parameters: (the energy unit is eV, the length unit A):  $V_{NN}^{p}$  0.57,  $V_{NNN}^{p}$  8:8 10<sup>3</sup>,  $k_{p}f^{2}$  0:72, and 3:7. The large value of means that the relaxation of the strain is very weak (see Fig. 1) so there is no size calibration with the above parameters. The crucial parameter , however, can strongly vary in di erent systems. For example, according to our estimates based on the potentials of Ref.<sup>23</sup>, in Pt/Co ' 0:32 is an order of magnitude smaller. Because of this the system is quite close to the self-assembly but the mis t strain is still too small. To enhance the m is t, in our model calculations we assumed that the Co underlayer is further com pressed (e.g., by m eans of deposition on an appropriate substrate) by the factor 1 (see Table IV and Fig.2). But for below the critical value c 2% there is no self-assembly at T = 0 because there is no minimum in  $E_1(T = 0)=1$  (see Ref.<sup>5</sup>). However, because of the T-dependent entropic contribution in the e ective energy (3), slightly below  $_{\rm c}$  the system does exhibit the self-assembly at intermediate temperatures which, however, disappears as  $T \downarrow 0$  (see Fig. 2). Thus, our model predicts a new phenomenon which may be called the entropy driven transient self-assembly. For higher values of strain the  $E_1(T = 0)=1$  curve does have a minimum (see Fig. 2) in which case the qualitative analysis of Ref.<sup>5</sup> fully applies.

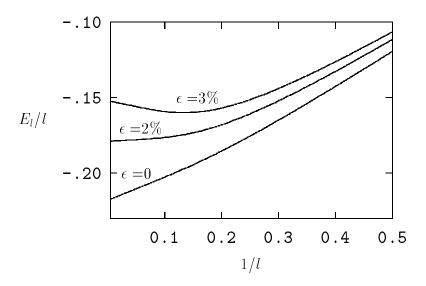


FIG.2: Length dependence of the reduced energy at zero tem perature of the Ptm on atom ic chains for di erent values of compression of the C o substrate.

## V. CONCLUSION

In this paper we considered a simple model of strained 1D epitaxy and have shown that sim ilarly to the 2D case the mechanism of self-assembly and size calibration proposed in Ref.<sup>5</sup> is operative also in this case. We considered only two explicit examples for which there exist in literature reliable interatom ic potentials and in one system already found the size calibration for stressed substrate. In our opinion, this shows that the above phenom ena should be as common in 1D as they are in 2D heteroepitaxy. Further argument in favor of this conclusion is that for the size calibration to be plausible the crucial parameter  $= k_s = k_p$ should be as small as possible. This favors small values of  $k_s$ . However, the geometry considered in the present paper is not quite favorable because of the high coordination of the atom s deposited at the steps with 5 NN atom s of the substrate (see Ref.<sup>24</sup>) which enhances  $k_s$ . It may be hoped that with lower coordination of the deposited atom s (as in the case of 1D structures of Ref.<sup>7</sup>) the conditions for the size calibration will be more favorable. A cknow ledgm ents

One of us (VT) expresses his gratitude to University Louis Pasteur de Strasbourg and IPCMS for their hospitality.

APPENDIX A

According to Eq. (7)

0								1	
D 1 = D 1	1+	1	0	:::	0	0	0		
BBBB	1	2+	1	0	:::	0	0		
1 B B B B B	0	1	2+	1	0	:::	0	CC	
$D_1 = B_B$	:	÷	۰.	·	•.	:	:	;	(A1)
1 M M M M C M	0	:::	0	1	2+	1	0		
BBBB	0	0	:::	0	1	2+	1		
اللا اللا اللا اللا الا الا الا الا الا	0	0	0	::: / 7	0	1	1+	CCCCA	
				1				<b>-</b> }	

where  $= k_s = k_p$ . Because matrices D<sub>1</sub> are tri-diagonal, their determ inants satisfy recurrence relations which can be used to calculate all quantities entering Eqs. (4) and (5). The diagonal element of the matrix  $G_1 = 1 = D_1$  is

$$G_{1}^{(0)} = r_{1} = \det D_{1};$$
 (A2)

where  $r_{l-1}$  is the determ inant of the matrix obtained from  $D_1$  by crossing out its strow and the strolum n:

Expanding det  $D_1$  with respect to the strow we get

$$det D_{1} = (1 + )r_{1 1} r_{1 2}; \qquad (A 4)$$

Comparing this with Eq. (A2) we get

$$G_{1}^{(0)} = 1 = (1 + d_{11});$$
 (A5)

where  $d_{1} = r_{1} = r_{1} = r_{1}$ . Now, expanding determ inant Eq. (A 3) with respect to the elements of the rst row we get the following three term recurrence relation

$$r_{1 1} = (2 + )r_{1 2} r_{1 3}$$
: (A 6)

But because Eq. (A 2) includes only the ratio  $r_{1 2}=r_{1 1}$  by dividing Eq. (A 6) by  $r_{1 2}$  we can transform it to a simpler form

$$\frac{1}{d_{1\,1}} = 2 + d_{1\,2}; \tag{A7}$$

The o -diagonal matrix element  $G_1^{(1)}$  of the inverse matrix  $G_1$  is equal to the ratio of the determ inant of the matrix obtained from  $D_1$  by crossing out its rst row and the last colum n multiplied by  $(1)^{l+1}$  and divided by det  $D_1$ . As is easy to see from Eq. (A1) the matrix thus obtained is a triangular matrix with the diagonal elements being all equal to -1. Hence its determ inant is equal to  $(1)^{l+1}$  and

$$G_{1}^{(l \ 1)} = 1 = \det D_{1} = \det G_{1}$$
: (A 8)

From Eq. (A4) we get

$$G_{1}^{(l-1)} = \frac{1}{\det D_{1}} = \frac{1}{r_{l-1}(1+d_{l-1})} = \frac{b_{l-1}}{1+d_{l-1}} = b_{l-1}G_{1}^{(0)}; \quad (A 9)$$

where  $b_{l-1} = 1 = r_{l-1} = d_{l-1}b_{l-2}$  (see the de nition of  $d_{l-1}$  above). Finally, making the shift l = 1 + 1 the above form ulas can be sum marized as

<sup>8</sup>  
<sup>6</sup> 
$$G_{l+1}^{(0)} = 1 = (1 + d_{1})$$
  
<sup>7</sup>  $G_{l+1}^{(0)} = \det G_{l+1} = G_{l+1}^{(0)} b_{l};$ 
(A 10)

where  $d_1$  and  $b_1$  are generated by the recursion relations

$$d_{l+1} = 1 = (2 + d_l)$$
 and  $b_{l+1} = d_{l+1}b_l$  (A 11)

initialized by  $d_0 = b_0 = 1$ .

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